



Welcome to [E-XFL.COM](https://www.e-xfl.com)

### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

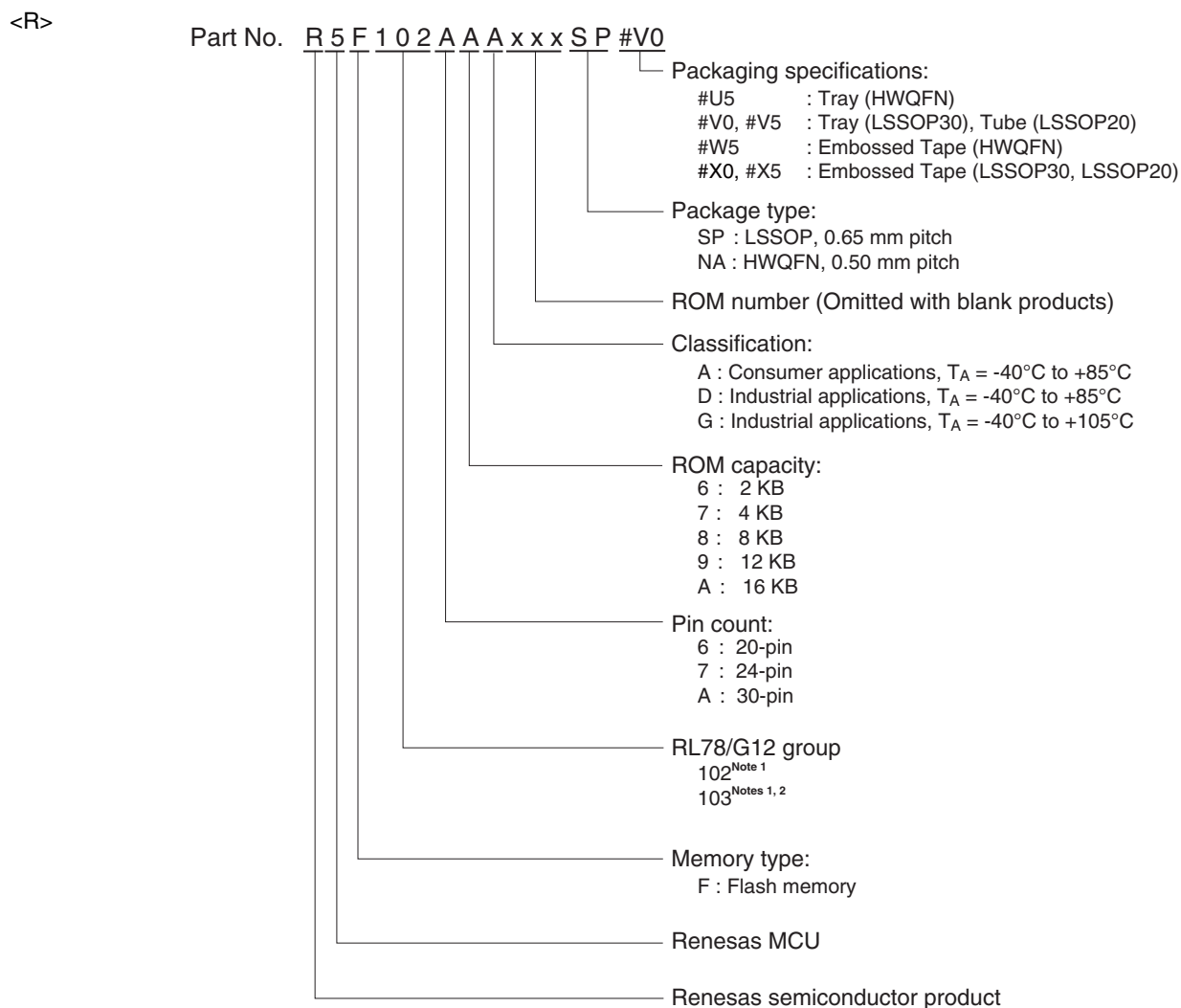
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	18
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	768 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-WFQFN Exposed Pad
Supplier Device Package	24-HWQFN (4x4)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10378ana-w5">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10378ana-w5</a>

## 1.2 List of Part Numbers

Figure 1-1. Part Number, Memory Size, and Package of RL78/G12



- Notes**
- For details about the differences between the R5F102 products and the R5F103 products of RL78/G12, see **1.1 Differences between the R5F102 Products and the R5F103 Products**.
  - Products only for "A: Consumer applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )" and "D: Industrial applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )"

### 1.3.2 On-chip oscillator characteristics

(1) High-speed on-chip oscillator oscillation frequency of the R5F102 products

Oscillator	Condition	MIN	MAX	Unit
High-speed on-chip oscillator oscillation frequency accuracy	$T_A = -20$ to $+85$ °C	-1.0	+1.0	%
	$T_A = -40$ to $-20$ °C	-1.5	+1.5	
	$T_A = +85$ to $+105$ °C	-2.0	+2.0	

(2) High-speed on-chip oscillator oscillation frequency of the R5F103 products

Oscillator	Condition	MIN	MAX	Unit
High-speed on-chip oscillator oscillation frequency accuracy	$T_A = -40$ to $+85$ °C	-5.0	+5.0	%

### 1.3.3 Peripheral Functions

The following are differences in peripheral functions between the R5F102 products and the R5F103 products.

RL78/G12		R5F102 product		R5F103 product	
		20, 24 pin product	30 pin product	20, 24 pin product	30 pin product
Serial interface	UART	1 channel	3 channels	1 channel	
	CSI	2 channels	3 channels	1 channel	
	Simplified I <sup>2</sup> C	2 channels	3 channels	None	
DMA function		2 channels		None	
Safety function	CRC operation	Yes		None	
	RAM guard	Yes		None	
	SFR guard	Yes		None	

## 1.7 Outline of Functions

This outline describes the function at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

<R>

Item		20-pin		24-pin		30-pin	
		R5F1026x	R5F1036x	R5F1027x	R5F1037x	R5F102Ax	R5F103Ax
Code flash memory		2 to 16 KB <sup>Note 1</sup>		4 to 16 KB			
Data flash memory		2 KB	–	2 KB	–	2 KB	–
RAM		256 B to 1.5 KB		512 B to 1.5 KB		512 B to 2KB	
Address space		1 MB					
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode : 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
	High-speed on-chip oscillator clock	HS (High-speed main) mode : 1 to 24 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
Low-speed on-chip oscillator clock		15 kHz (TYP)					
General-purpose register		(8-bit register × 8) × 4 banks					
Minimum instruction execution time		0.04167 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 24 MHz operation)					
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)					
Instruction set		• Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits × 8 bits) • Rotate, barrel shift, and bit manipulation (set, reset, test, and Boolean operation), etc.					
I/O port	Total	18		22		26	
	CMOS I/O	12 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 4)		16 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 5)		21 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 9)	
	CMOS input	4		4		3	
	N-ch open-drain I/O (6 V tolerance)	2					
Timer	16-bit timer	4 channels				8 channels	
	Watchdog timer	1 channel					
	12-bit Interval timer	1 channel					
	Timer output	4 channels (PWM outputs: 3 <sup>Note 3</sup> )				8 channels (PWM outputs: 7 <sup>Note 3</sup> , <sup>Note 2</sup> )	

**Notes** 1. The self-programming function cannot be used in the R5F10266 and R5F10366.

2. The maximum number of channels when PIOR0 is set to 1.

3. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves). (See **6.9.3 Operation as multiple PWM output function.**)

**Caution** When the flash memory is rewritten via a user program, the code flash area and RAM area are used because each library is used. When using the library, refer to RL78 Family Flash Self Programming Library Type01 User's Manual and RL78 Family Data Flash Library Type04 User's Manual.

## 2.3 DC Characteristics

## 2.3.1 Pin characteristics

(T<sub>A</sub> = –40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

(1/4)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	20-, 24-pin products: Per pin for P00 to P03 <sup>Note 4</sup> , P10 to P14, P40 to P42  30-pin products: Per pin for P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147			–10.0 <sup>Note 2</sup>	mA
		20-, 24-pin products: Total of P40 to P42	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		–30.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		–6.0	mA
		30-pin products: Total of P00, P01, P40, P120 (When duty ≤ 70% <sup>Note 3</sup> )	1.8 V ≤ V <sub>DD</sub> < 2.7 V		–4.5	mA
		20-, 24-pin products: Total of P00 to P03 <sup>Note 4</sup> , P10 to P14	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		–80.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		–18.0	mA
		30-pin products: Total of P10 to P17, P30, P31, P50, P51, P147 (When duty ≤ 70% <sup>Note 3</sup> )	1.8 V ≤ V <sub>DD</sub> < 2.7 V		–10.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			–100	mA
	I <sub>OH2</sub>	Per pin for P20 to P23			–0.1	mA
		Total of all pins			–0.4	mA

**Notes** 1. value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub> pin to an output pin.

2. However, do not exceed the total current value.

3. The output current value under conditions where the duty factor ≤ 70%.

If duty factor > 70%: The output current value can be calculated with the following expression (where n represents the duty factor as a percentage).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = –10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7) / (80 \times 0.01) \cong -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

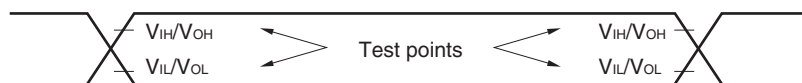
4. 24-pin products only.

**Caution** P10 to P12 and P41 for 20-pin products, P01, P10 to P12, and P41 for 24-pin products, and P00, P10 to P15, P17, and P50 for 30-pin products do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.5 Peripheral Functions Characteristics

### AC Timing Test Point



### 2.5.1 Serial array unit

#### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Transfer rate				$f_{MCK}/6$		$f_{MCK}/6$	bps
Note 1		Theoretical value of the maximum transfer rate $f_{CLK} = f_{MCK}$ <sup>Note2</sup>		4.0		1.3	Mbps

**Notes** 1. Transfer rate in the SNOOZE mode is 4800 bps only.

2. The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:

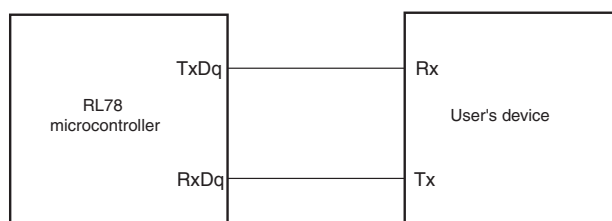
HS (high-speed main) mode: 24 MHz ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

16 MHz ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

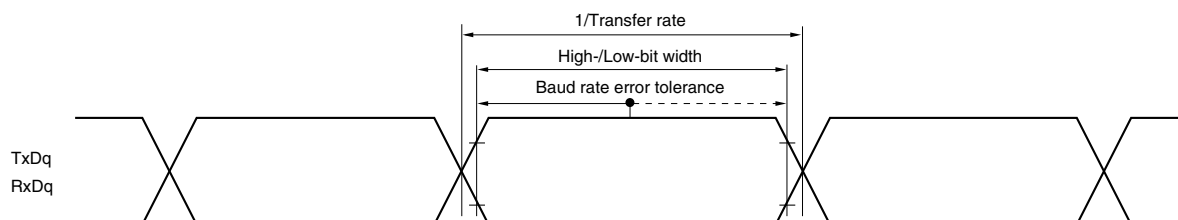
LS (low-speed main) mode: 8 MHz ( $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remarks** 1. q: UART number (q = 0 to 2), g: PIM, POM number (g = 0, 1)

2.  $f_{MCK}$ : Serial array unit operation clock frequency

(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

**(2) During communication at same potential (CSI mode) (master mode, SCK00... internal clock output, corresponding CSI00 only)**

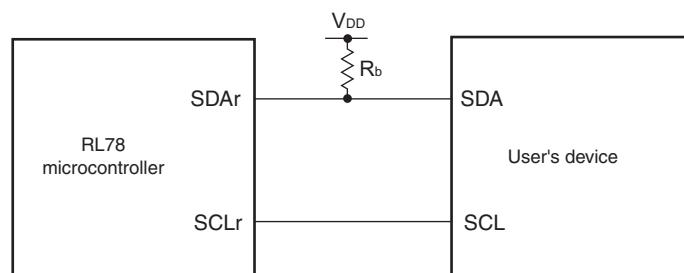
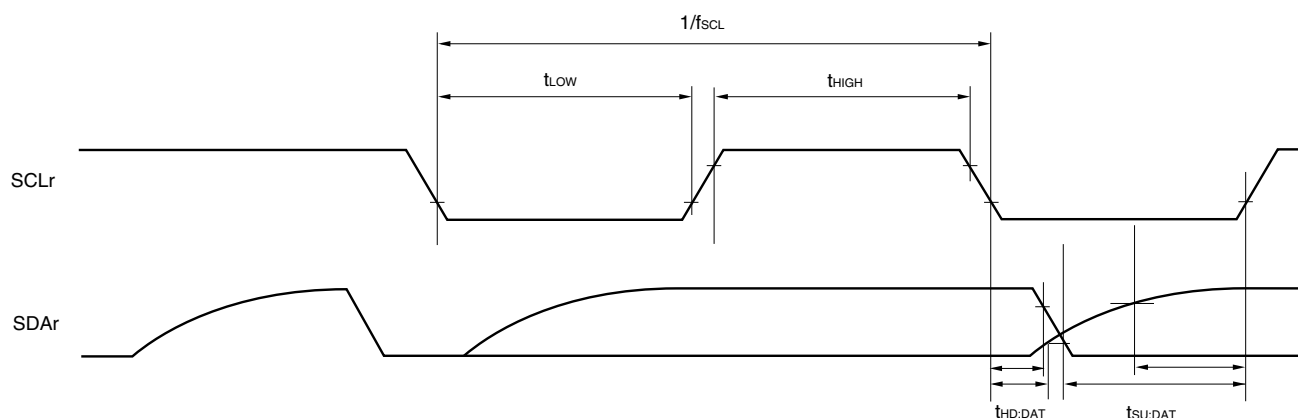
**(T<sub>A</sub> = –40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
SCK00 cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 2/f <sub>CLK</sub>	83.3		250		ns
SCK00 high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	t <sub>KCY1</sub> /2–7		t <sub>KCY1</sub> /2–50		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	t <sub>KCY1</sub> /2–10		t <sub>KCY1</sub> /2–50		ns
SI00 setup time (to SCK00↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	23		110		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	33		110		ns
SI00 hold time (from SCK00↑) <sup>Note 2</sup>	t <sub>KSI1</sub>		10		10		ns
Delay time from SCK00↓ to SO00 output <sup>Note 3</sup>	t <sub>KSO1</sub>	C = 20 pF <sup>Note 4</sup>		10		10	ns

- Notes**
1. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The SI00 setup time becomes “to SCK00↓” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  2. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The SI00 hold time becomes “from SCK00↓” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  3. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The delay time to SO00 output becomes “from SCK00↑” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  4. C is the load capacitance of the SCK00 and SO00 output lines.

**Caution** Select the normal input buffer for the SI00 pin and the normal output mode for the SO00 and SCK00 pins by using port input mode register 1 (PIM1) and port output mode register 1 (POM1).

- Remarks**
1. This specification is valid only when CSI00's peripheral I/O redirect function is not used.
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register 0 (SPS0) and the CKS00 bit of serial mode register 00 (SMR00).)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**

- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SDAr) pull-up resistance  
 $C_b$  [F]: Communication line (SCLr, SDAr) load capacitance
  2.  $r$ : IIC number ( $r = 00, 01, 11, 20$ ),  $h$ : = POM number ( $h = 0, 1, 4, 5$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register  $m$  (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  $m$ : Unit number ( $m = 0, 1$ ),  $n$ : Channel number ( $0, 1, 3$ ))
  4. Simplified I<sup>2</sup>C mode is supported only by the R5F102 products.



**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Transfer rate <small>Note4</small>		Reception					
		4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V		f <sub>MCK</sub> /6 <small>Note1</small>		f <sub>MCK</sub> /6 <small>Note1</small>	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>		4.0		1.3	Mbps
		2.7 V ≤ V <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V		f <sub>MCK</sub> /6 <small>Note1</small>		f <sub>MCK</sub> /6 <small>Note1</small>	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>		4.0		1.3	Mbps
		1.8 V ≤ V <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V		f <sub>MCK</sub> /6 <small>Notes1, 2</small>		f <sub>MCK</sub> /6 <small>Notes1, 2</small>	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>		4.0		1.3	Mbps
		Transmission					
		4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V		<b>Note4</b>		<b>Note4</b>	bps
		Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V		2.8 <small>Note5</small>		2.8 <small>Note5</small>	Mbps
		2.7 V ≤ V <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V		<b>Note6</b>		<b>Note6</b>	bps
		Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V		1.2 <small>Note7</small>		1.2 <small>Note7</small>	Mbps
		1.8 V ≤ V <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V		<b>Notes 2, 8</b>		<b>Notes 2, 8</b>	bps
		Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V		0.43 <small>Note9</small>		0.43 <small>Note9</small>	Mbps

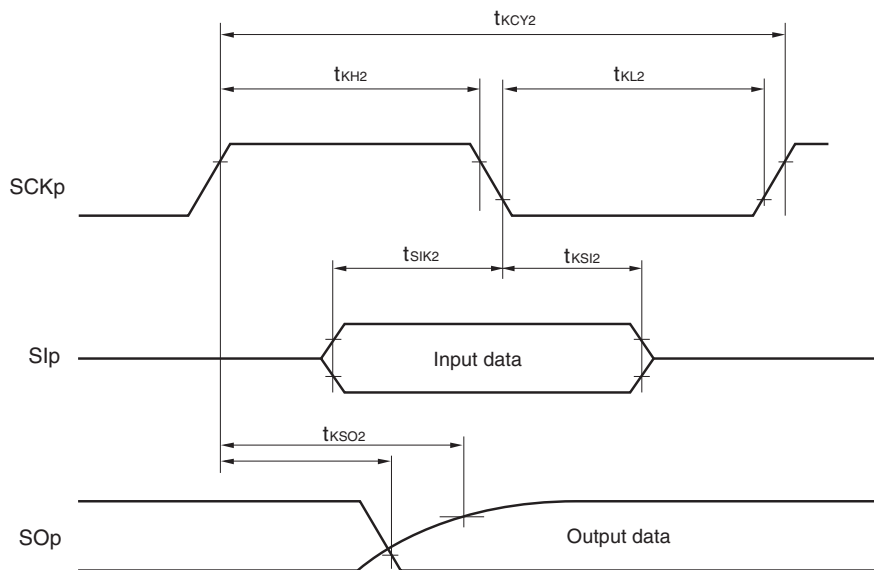
**Notes** 1. Transfer rate in the SNOOZE mode is 4800 bps only.2. Use it with V<sub>DD</sub> ≥ V<sub>b</sub>.3. The maximum operating frequencies of the CPU/peripheral hardware clock (f<sub>CLK</sub>) are:HS (high-speed main) mode: 24 MHz (2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V)16 MHz (2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V)LS (low-speed main) mode: 8 MHz (1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V)4. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.Expression for calculating the transfer rate when 4.0 V ≤ V<sub>DD</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark** p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

## 3.3 DC Characteristics

## 3.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

(1/4)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	20-, 24-pin products: Per pin for P00 to P03 <sup>Note 4</sup> , P10 to P14, P40 to P42  30-pin products: Per pin for P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147			-3.0 <sup>Note 2</sup>	mA
		20-, 24-pin products: Total of P40 to P42	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		-9.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		-6.0	mA
		30-pin products: Total of P00, P01, P40, P120 (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> < 2.7 V		-4.5	mA
		20-, 24-pin products: Total of P00 to P03 <sup>Note 4</sup> , P10 to P14	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		-27.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		-18.0	mA
		30-pin products: Total of P10 to P17, P30, P31, P50, P51, P147 (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> < 2.7 V		-10.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			-36.0	mA
	I <sub>OH2</sub>	Per pin for P20 to P23			-0.1	mA
		Total of all pins			-0.4	mA

**Notes** 1. value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub> pin to an output pin.

2. However, do not exceed the total current value.

3. The output current value under conditions where the duty factor ≤ 70%.

If duty factor > 70%: The output current value can be calculated with the following expression (where n represents the duty factor as a percentage).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \cong -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

4. 24-pin products only.

**Caution** P10 to P12 and P41 for 20-pin products, P01, P10 to P12, and P41 for 24-pin products, and P00, P10 to P15, P17, and P50 for 30-pin products do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD2</sub> <sup>Note 2</sup>	HALT mode	HS (High-speed main) mode <sup>Note 6</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		440	2230	μA
					V <sub>DD</sub> = 3.0 V		440	2230	
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		400	1650	μA
					V <sub>DD</sub> = 3.0 V		400	1650	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		190	1010	μA
					Resonator connection		260	1090	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		190	1010	μA
					Resonator connection		260	1090	
	I <sub>DD3</sub> <sup>Note 5</sup>	STOP mode	T <sub>A</sub> = −40°C				0.19	0.50	μA
			T <sub>A</sub> = +25°C				0.24	0.50	
			T <sub>A</sub> = +50°C				0.32	0.80	
			T <sub>A</sub> = +70°C				0.48	1.20	
			T <sub>A</sub> = +85°C				0.74	2.20	
			T <sub>A</sub> = +105°C				1.50	10.20	

- Notes**
1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator clock is stopped.
  4. When high-speed system clock is stopped.
  5. Not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS (High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency
  3. Except temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ , other than STOP mode

## (2) 30-pin products

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <small>Note 1</small>	I <sub>DD2</sub> <small>Note 2</small>	HALT mode	HS (High-speed main) mode <small>Note 6</small>	f <sub>IH</sub> = 24 MHz <small>Note 4</small>	V <sub>DD</sub> = 5.0 V		440	2300	μA
					V <sub>DD</sub> = 3.0 V		440	2300	
				f <sub>IH</sub> = 16 MHz <small>Note 4</small>	V <sub>DD</sub> = 5.0 V		400	1700	μA
					V <sub>DD</sub> = 3.0 V		400	1700	
				f <sub>MX</sub> = 20 MHz <small>Note 3</small> , V <sub>DD</sub> = 5.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 20 MHz <small>Note 3</small> , V <sub>DD</sub> = 3.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 10 MHz <small>Note 3</small> , V <sub>DD</sub> = 5.0 V	Square wave input		190	1020	μA
					Resonator connection		260	1100	
				f <sub>MX</sub> = 10 MHz <small>Note 3</small> , V <sub>DD</sub> = 3.0 V	Square wave input		190	1020	μA
					Resonator connection		260	1100	
I <sub>DD3</sub> <small>Note 5</small>	STOP mode	T <sub>A</sub> = −40°C					0.18	0.50	μA
		T <sub>A</sub> = +25°C					0.23	0.50	
		T <sub>A</sub> = +50°C					0.30	1.10	
		T <sub>A</sub> = +70°C					0.46	1.90	
		T <sub>A</sub> = +85°C					0.75	3.30	
		T <sub>A</sub> = +105°C					2.94	15.30	

**Notes 1.** Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

**2.** During HALT instruction execution by flash memory.

**3.** When high-speed on-chip oscillator clock is stopped.

**4.** When high-speed system clock is stopped.

**5.** Not including the current flowing into the 12-bit interval timer and watchdog timer.

**6.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS (High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

**Remarks 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

**2.**  $f_{IH}$ : high-speed on-chip oscillator clock frequency

**3.** Except STOP mode, temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ .

## 3.4 AC Characteristics

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>CY</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (High-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
		During self programming	HS (High-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
External main system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			1.0		16.0	MHz
External main system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			30			ns
TI00 to TI07 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>				1/f <sub>MCK</sub> + 10			ns
TO00 to TO07 output frequency	f <sub>TO</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V					12	MHz
		2.7 V ≤ V <sub>DD</sub> < 4.0 V					8	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V					4	MHz
PCLBUZ0, or PCLBUZ1 output frequency	f <sub>PCL</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V					16	MHz
		2.7 V ≤ V <sub>DD</sub> < 4.0 V					8	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V					4	MHz
INTP0 to INTP5 input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>				1			μs
KR0 to KR9 input available width	t <sub>KR</sub>				250			ns
RESET low-level width	t <sub>RSL</sub>				10			μs

**Remark** fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the timer clock select register 0 (TPS0) and the CKS0n bit of timer mode register 0n (TMR0n). n: Channel number (n = 0 to 7))

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)**

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

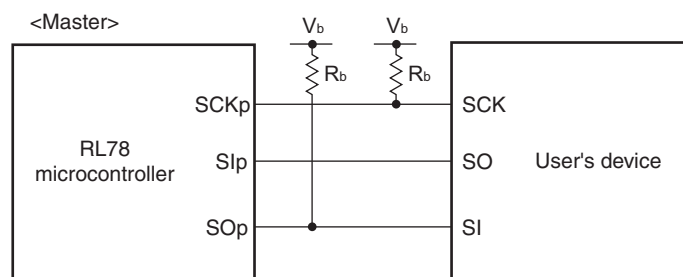
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↓) <small>Note</small>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	88		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	88		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	220		ns
Slp hold time (from SCKp↓) <small>Note</small>	$t_{KSI1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	38		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	38		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	38		ns
Delay time from SCKp↑ to SOp output <small>Note</small>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		50	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		50	ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		50	ns

**Note** When  $DAP_{mn} = 0$  and  $CKP_{mn} = 1$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 0$ .

- Cautions 1.** Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.
- 2.** CSI01 and CSI11 cannot communicate at different potential.

- Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage
- 2.** p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

**CSI mode connection diagram (during communication at different potential)**



**(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)**  
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

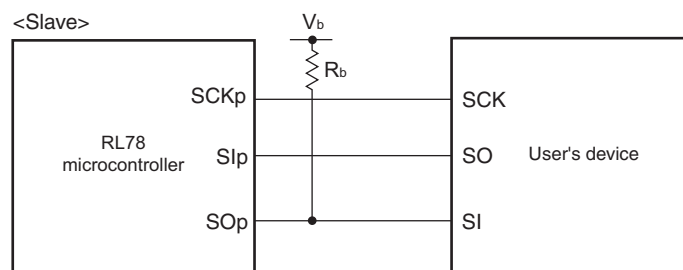
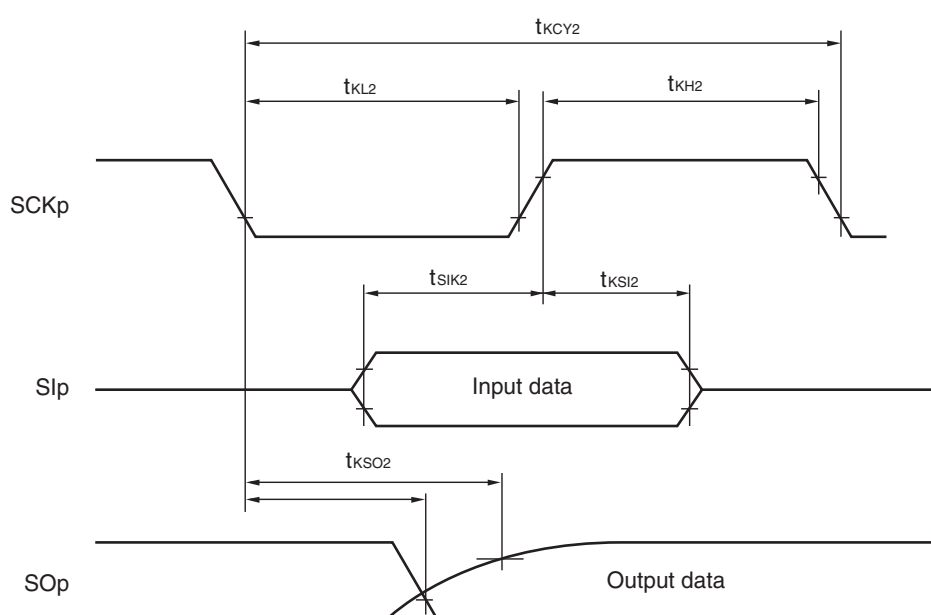
Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCKp cycle time <sup>Note 1</sup>	$t_{KCY2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$	$20\text{ MHz} < f_{MCK} \leq 24\text{ MHz}$	$24/f_{MCK}$		ns
			$8\text{ MHz} < f_{MCK} \leq 20\text{ MHz}$	$20/f_{MCK}$		ns
			$4\text{ MHz} < f_{MCK} \leq 8\text{ MHz}$	$16/f_{MCK}$		ns
			$f_{MCK} \leq 4\text{ MHz}$	$12/f_{MCK}$		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$	$20\text{ MHz} < f_{MCK} \leq 24\text{ MHz}$	$32/f_{MCK}$		ns
			$16\text{ MHz} < f_{MCK} \leq 20\text{ MHz}$	$28/f_{MCK}$		ns
			$8\text{ MHz} < f_{MCK} \leq 16\text{ MHz}$	$24/f_{MCK}$		ns
			$4\text{ MHz} < f_{MCK} \leq 8\text{ MHz}$	$16/f_{MCK}$		ns
			$f_{MCK} \leq 4\text{ MHz}$	$12/f_{MCK}$		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$	$20\text{ MHz} < f_{MCK} \leq 24\text{ MHz}$	$72/f_{MCK}$		ns
			$16\text{ MHz} < f_{MCK} \leq 20\text{ MHz}$	$64/f_{MCK}$		ns
			$8\text{ MHz} < f_{MCK} \leq 16\text{ MHz}$	$52/f_{MCK}$		ns
			$4\text{ MHz} < f_{MCK} \leq 8\text{ MHz}$	$32/f_{MCK}$		ns
			$f_{MCK} \leq 4\text{ MHz}$	$20/f_{MCK}$		ns
SCKp high-/low-level width	$t_{KH2}$ , $t_{KL2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$		$t_{KCY2}/2 - 24$		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$		$t_{KCY2}/2 - 36$		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$		$t_{KCY2}/2 - 100$		ns
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 2</sup>	$t_{SIK2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_{DD} \leq 4.0\text{ V}$		$1/f_{MCK} + 40$		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$		$1/f_{MCK} + 40$		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_{DD} \leq 2.0\text{ V}$		$1/f_{MCK} + 60$		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 3</sup>	$t_{KSI2}$			$1/f_{MCK} + 62$		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 4</sup>	$t_{KSO2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$			$2/f_{MCK} + 240$	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$			$2/f_{MCK} + 428$	ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$			$2/f_{MCK} + 1146$	ns

**Notes** 1. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp $\downarrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp $\downarrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp $\uparrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

- Cautions**
1. Select the TTL input buffer for the Slp and SCKp pins and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). **For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.**
  2. CSI01 and CSI11 cannot communicate at different potential.



**CSI mode connection diagram (during communication at different potential)**
**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**


- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SO<sub>p</sub>) pull-up resistance,  $C_b$  [F]: Communication line (SO<sub>p</sub>) load capacitance,  $V_b$  [V]: Communication line voltage
  2. p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn))

## 3.5.2 Serial interface IICA

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) mode				Unit
			Standard Mode		Fast Mode		
			MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz			0	400	kHz
		Normal mode: f <sub>CLK</sub> ≥ 1 MHz	0	100			kHz
Setup time of restart condition	t <sub>SU:STA</sub>		4.7		0.6		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>		4.0		0.6		μs
Hold time when SCLA0 = “L”	t <sub>LOW</sub>		4.7		1.3		μs
Hold time when SCLA0 = “H”	t <sub>HIGH</sub>		4.0		0.6		μs
Data setup time (reception)	t <sub>SU:DAT</sub>		250		100		ns
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>		0	3.45	0	0.9	μs
Setup time of stop condition	t <sub>SU:STO</sub>		4.0		0.6		μs
Bus-free time	t <sub>BUF</sub>		4.7		1.3		μs

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.

<R> 2. The maximum value (MAX.) of  $t_{HD:DAT}$  is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

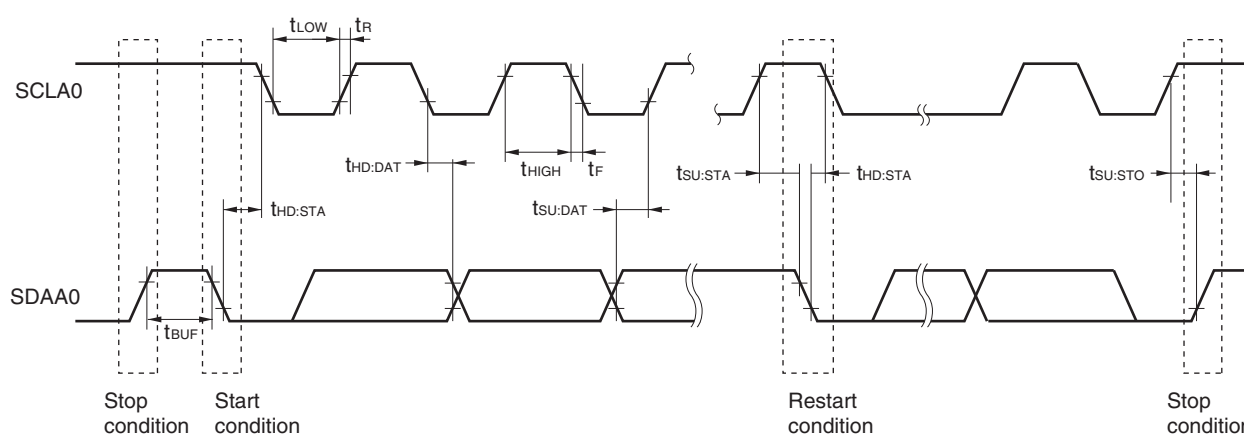
**Caution** Only in the 30-pin products, the values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics ( $I_{OH1}$ ,  $I_{OL1}$ ,  $V_{OH1}$ ,  $V_{OL1}$ ) must satisfy the values in the redirect destination.

**Remark** The maximum value of  $C_b$  (communication line capacitance) and the value of  $R_b$  (communication line pull-up resistor) at that time in each mode are as follows.

Normal mode:  $C_b = 400\text{ pF}$ ,  $R_b = 2.7\text{ k}\Omega$

Fast mode:  $C_b = 320\text{ pF}$ ,  $R_b = 1.1\text{ k}\Omega$

IICA serial transfer timing



(3) When reference voltage (+) =  $V_{DD}$  (ADREFP1 = 0, ADREFP0 = 0), reference voltage (–) =  $V_{SS}$  (ADREFM = 0), target pin: ANI0 to ANI3, ANI16 to ANI22, internal reference voltage, and temperature sensor output voltage

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $V_{DD}$ , Reference voltage (–) =  $V_{SS}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution		1.2	$\pm 7.0$	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI0 to ANI3, ANI16 to ANI22	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.375	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.5625	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	EZS	10-bit resolution			$\pm 0.60$	%FSR
Full-scale error <sup>Notes 1, 2</sup>	EFS	10-bit resolution			$\pm 0.60$	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution			$\pm 4.0$	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution			$\pm 2.0$	LSB
Analog input voltage	V <sub>AIN</sub>	ANI0 to ANI3, ANI16 to ANI22	0		$V_{DD}$	V
		Internal reference voltage (HS (high-speed main) mode)	V <sub>BGR</sub> <sup>Note 3</sup>			V
		Temperature sensor output voltage (HS (high-speed main) mode)	V <sub>TMPS25</sub> <sup>Note 3</sup>			V

**Notes** 1. Excludes quantization error ( $\pm 1/2$  LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **29.6.2 Temperature sensor/internal reference voltage characteristics**.

Rev.	Date	Description	
		Page	Summary
2.00	Sep 06, 2013	55	Modification of description and Notes 3 and 4 in 2.6.1 (3)
		56	Modification of description and Notes 3 and 4 in 2.6.1 (4)
		57	Modification of table in 2.6.2 Temperature sensor/internal reference voltage characteristics
		57	Modification of table and Note in 2.6.3 POR circuit characteristics
		58	Modification of table in 2.6.4 LVD circuit characteristics
		59	Modification of table of LVD detection voltage of interrupt & reset mode
		59	Modification of number and title to 2.6.5 Power supply voltage rising slope characteristics
		61	Modification of table, figure, and Remark in 2.10 Timing of Entry to Flash Memory Programming Modes
		62 to 103	Addition of products of industrial applications (G: T <sub>A</sub> = -40 to +105°C)
		104 to 106	Addition of products of industrial applications (G: T <sub>A</sub> = -40 to +105°C)
2.10	Mar 25, 2016	6	Modification of Figure 1-1 Part Number, Memory Size, and Package of RL78/G12
		7	Modification of Table 1-1 List of Ordering Part Numbers
		8	Addition of product name (RL78/G12) and description (Top View) in 1.4.1 20-pin products
		9	Addition of product name (RL78/G12) and description (Top View) in 1.4.2 24-pin products
		10	Addition of product name (RL78/G12) and description (Top View) in 1.4.3 30-pin products
		15	Modification of description in 1.7 Outline of Functions
		16	Modification of description, and addition of target products
		52	Modification of note 2 in 2.5.2 Serial interface IICA
		60	Modification of title and note, and addition of caution in 2.7 RAM Data Retention Characteristics
		60	Modification of conditions in 2.8 Flash Memory Programming Characteristics
		62	Modification of description, and addition of target products and remark
		94	Modification of note 2 in 3.5.2 Serial interface IICA
		102	Modification of title and note in 3.7 RAM Data Retention Characteristics
		102	Modification of conditions in 3.8 Flash Memory Programming Characteristics
		104 to 106	Addition of package name

All trademarks and registered trademarks are the property of their respective owners.

SuperFlash is a registered trademark of Silicon Storage Technology, Inc. in several countries including the United States and Japan.

Caution: This product uses SuperFlash® technology licensed from Silicon Storage Technology, Inc.

## Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
  2. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
  3. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
  4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
  5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.  
"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc.  
"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc.  
Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for which the product is not intended by Renesas Electronics.
  6. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
  7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by you.
  8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
  9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
  10. It is the responsibility of the buyer or distributor of Renesas Electronics products, who distributes, disposes of, or otherwise places the product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, Renesas Electronics assumes no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
  11. This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
  12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



### SALES OFFICES

### Renesas Electronics Corporation

<http://www.renesas.com>

Refer to "<http://www.renesas.com/>" for the latest and detailed information.

#### California Eastern Laboratories, Inc.

4590 Patrick Henry Drive, Santa Clara, California 95054-1817, U.S.A.  
Tel: +1-408-919-2500, Fax: +1-408-988-0279

#### Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K  
Tel: +44-1628-585-100, Fax: +44-1628-585-900

#### Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

#### Renesas Electronics (China) Co., Ltd.

Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

#### Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

#### Renesas Electronics Hong Kong Limited

Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

#### Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

#### Renesas Electronics Singapore Pte. Ltd.

80 Bendemeer Road, Unit #06-02, Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

#### Renesas Electronics Malaysia Sdn.Bhd.

Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

#### Renesas Electronics India Pvt. Ltd.

No.777C, 100 Feet Road, HAL II Stage, Indiranagar, Bangalore, India  
Tel: +91-80-67208700, Fax: +91-80-67208777

#### Renesas Electronics Korea Co., Ltd.

12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5141